The electronic structure of $CuSiO_3$ – a possible candidate for a new inorganic spin-Peierls compound ?

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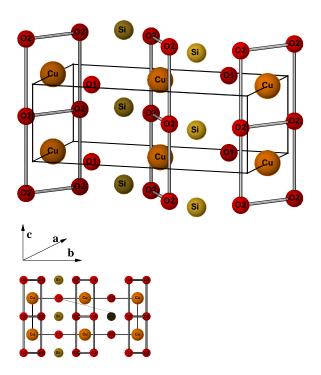
Electronic structure calculations are presented for the well-known CuGeO₃ and the recently discovered isostructural CuSiO₃ compounds. The magnitude of the dispersion in chain direction is considerably smaller for CuSiO₃, whereas the main interchain couplings are rather similar in both compounds. Starting from extended one-band tight-binding models fitted to the bandstructures, the exchange integrals were estimated for both compounds in terms of a spatially anisotropic Heisenberg model. Remarkable frustrating second neighbor couplings are found both for intra- and inter-chain interactions. A magnetic moment of about 0.35 μ_B is predicted for CuSiO₃ in the Néel state.

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Low-dimensional spin systems such as chains or ladders are of fundamental interest for contemporary solid state physics due to their peculiar electronic and magnetic properties. During the last years, many related materials have been found within the cuprate family, famous for the high temperature superconductivity. All cuprates contain CuO₄ plaquettes. In most cases it is energetically favorable to connect these plaquettes by the formation of chains or planes. According to the number (n = 1, 2) of oxygen atoms shared by adjacent plaquettes, these compounds can be classified as so-called edge-shared (n = 2)or corner-shared (n = 1) compounds.

Obviously, the type of sharing affects strongly the physical properties of the compounds under consideration. For example, corner sharing leads to strong antiferromagnetic coupling between neighboring plaquettes compared with the weak inter-chain interactions.¹ As a result, the straight CuO₃ chain in Sr₂CuO₃ is the best known realization of the one-dimensional spin-1/2 Heisenberg model,² with an in-chain exchange coupling of about 2200 K, but with a Néel temperature of only 5 K and with an extremely small ordered magnetic moment of about 0.06 $\mu_{\rm B}$,³ both due to a small residual interchain exchange coupling. Spin-charge separation in the excitation spectra could be observed for Sr₂CuO₃ and for the double chain compound SrCuO₂.⁴

Somewhat surprisingly, in contrast to the similarity between different corner-shared chain compounds, the magnetic properties in the edge-shared chain family exhibit a remarkable variance. Thus, the edge-shared CuO_2 plaquettes in Li_2CuO_2 order antiferromagnetically with a ferromagnetic arrangement along those chains and with a large ordered moment of 0.9 $\mu_{\rm B}$,⁵ whereas the same chain in CuGeO₃ shows a spin-Peierls transition at low temperatures.⁶ Antiferromagnetically ordered chains were observed in $Cu_{1-x}Zn_xGeO_3$ for small concentrations of Zn impurities.⁷ It is noteworthy that, even for the intensively studied CuGeO₃, a consensus with respect to the quantitative description of competing or complementary interactions such as the inter-chain coupling, frustration and spin-phonon coupling has not been reached so



properties are the planar edge-shared CuO₂ chains running along **c**-direction. These chains are very similar to those of CuGeO₃. The Cu-O(2) bond length in CuSiO₃ (CuGeO₃) is 1.941 Å (1.942 Å), the Cu-O(2)-Cu bonding angle is 94° (99°).

Thus, the question arises, whether the very recently observed phase transition¹¹ near 8 K does point to a new inorganic spin-Peierls system or to another ordered state realized at low temperature. To get theoretical insight into possible scenarios, we present here comparative band-structure calculations and tight-binding examinations for CuSiO₃ and CuGeO₃. In this context we note that for the latter compound several (non full-potential) bandstructure calculation have been reported (e.g. in Ref. 12), but to our knowledge the inter-chain interaction has not been analyzed in detail.

The relevant electronic structure of these materials is very sensitive to details of hybridization and In order to obtain a realistic and charge balance. reliable hopping part of a tight binding Hamiltonian, band-structure calculations were performed using the full-potential nonorthogonal local-orbital minimum-basis scheme¹³ within the local density approximation (LDA). In the scalar relativistic calculations we used the exchange and correlation potential of Perdew and Zunger.¹⁴ Cu(4s, 4p, 3d), O(2s, 2p, 3d), Ge(3d, 4s, 4p, 4d) and Si(2p, 3s, 3p, 3d) states, respectively, were chosen as minimum basis set. All lower lying states were treated as core states. The inclusion of Ge 3d and Si 2p states in the valence states was necessary to account for nonnegligible core-core overlaps. The O and Si 3d as well as the Ge 4d states were taken into account to increase the completeness of the basis set. The spatial extension of the basis orbitals, controlled by a confining potential¹⁵ $(r/r_0)^4$, was optimized to minimize the total energy.

The results of the paramagnetic calculation¹⁶ for $CuSiO_3$ (see Fig. 2 (a)) and $CuGeO_3$ (see Fig. 2 (b); we find similar results as the non full-potential calculation of Ref. 12) show a valence band complex of about 10 eV width with two bands crossing the Fermi level in both cases. These two bands are well separated from the rest of the valence band complex and show mainly Cu 3d and O(2) 2p character in the analysis of the corresponding partial densities of states (not shown). We note that the occupancy of the two O(2) 2p orbitals along and perpendicular to the chain (lying in the plaquetteplanes) is rather different, but it is almost identical for the corresponding orbitals in both compounds. Therein, we found only a small admixture of O(1) 2p and Ge 4s and 4p states, respectively, with a total amount of few percent. The examination of the eigenstates of the latter bands at high symmetry points yields an antibonding character typical for cuprates. Here these relatively narrow antibonding bands are half-filled. Therefore, strong correlation effects can be expected which explain the experimentally observed insulating groundstate. Despite almost perfect qualitative one to one correspondence of all valence bands and main peak structures in the densities of states (DOS) (compare right panels in Fig. 2), the most important differences between both compounds

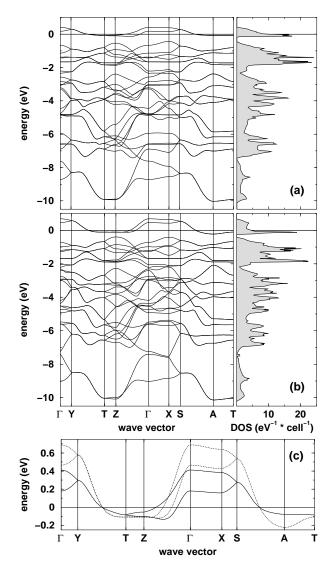


FIG. 2. Band structure and total density of states for CuSiO₃ (a), CuGeO₃ (b), and the zoomed antibonding bands (c) (CuSiO₃ full lines, CuGeO₃ dashed lines). The Fermi level is at zero energy. The notation of the symmetry points is as follows: Y = (010), T = (011), Z = (001), X = (100), S = (110), A = (111). The chain direction corresponds to Y–T, Z–T and S–A.

occur for the antibonding bands (shown in detail in Fig. 2(c)). Therefore, we restrict ourselves to the extended tight-binding analysis and the discussion of these antibonding bands.

The dispersion of these bands has been analyzed in terms of nearest neighbor transfer (NN), next nearest neighbor transfer (NNN) and higher neighbor terms in chain direction, but only NN hopping and a diagonal transition term between the CuO₂chains have been considered (see Fig. 3). Then, the corresponding dispersion relation takes the form

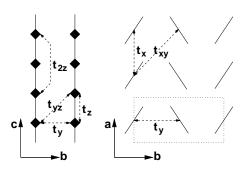


FIG. 3. Schematical chain and stack arrangement of CuO_2 -plaquettes, respectively, and considered transfer processes within the bc-plane (left panel) and in the ab-plane (right panel).

$$E(\vec{k}) = -2\left(\sum_{m=1,4} t_{mz}\cos(mz) + \cos(x)\left[t_x + 2t_{xz}\cos(z)\right] + \cos(y/2)\left[t_y + 2t_{yz}\cos(z) + 2t_{xy}\cos(x)\right]\right), \quad (1)$$

where $x = k_z a$, $y = k_y b$, $z = k_z c$. Notice that in our effective one-band description the upper band (see Fig. 2(c)) e.g. along Γ -X corresponds to $k_y = 0$, whereas the lower one corresponds to $k_y = 2\pi/b$. The assignment of the parameters has been achieved by two numerically independent procedures: By straightforward least square fitting of the whole antibonding band in all directions and by using the bandwidths, the slopes and the curvatures at special selected high symmetry points. The latter procedure has the advantage to be less affected by hybridization effects from lower lying bands near the bottom of the antibonding band (being of some relevance near the Z-point in Fig. 2).

	t_z	t_{2z}	t_{3z}	\mathbf{t}_x	t_y	t_{yz}
${\rm CuGeO_3}$	-175	-51	-5.5	-20	-34.1	-20.6
${\rm CuSiO}_3$	-88	-31	-4.5	-2.4	-36	-21.2

TABLE I. Transfer integrals t_i (in meV) of the extended one-band tight-binding model for CuGeO₃ and CuSiO₃. The remaining omitted terms from Eq. (1) were found to be irrelevant.

The results are shown in Tab. I. The errors can be estimated between 1% for the large and 10% for the small parameters from the difference of both mentioned above fitting procedures. The analyzed antibonding bands of both compounds exhibit a rather similar shape except near the Z-points, where the hybridization with lower lying bands produces an additional band-crossing for CuGeO₃ (see Fig. 2(c)). Recall that the main difference to the cornershared chains as e.g. in Sr₂CuO₃ is a much smaller inchain NN transfer due to the different geometry.

In spite of the qualitative similarity, the calculated values for the transfer integrals are quite different. The inchain dispersion is nearly twice as large for $CuGeO_3$ in comparison to CuSiO₃. This can be attributed mainly to the larger Cu-O-Cu bond angle in CuGeO₃ (99° and 94°, respectively). However, this geometrical effect is somewhat reduced by the different on-site energies of the oxygen orbitals along and perpendicular to the chain (lying in the plaquettes planes). The latter difference is reflected by the larger separation of the corresponding bands at the Z-point in CuSiO₃ (see Fig. 2).

The inter-chain dispersions in b direction are comparable. For both compounds, we find also rather significant diagonal hopping terms t_{yz} which are reflected by different dispersions along the X–S and the T–Z directions. Somewhat surprisingly, we found a sizeable dispersion in x-direction for CuGeO₃ but only a very weak one for the CuSiO₃ counterpart.

From the transfer integrals discussed above, we conclude that both compounds are not so well-defined quasi one-dimensional systems as compared to the cornershared CuO₃ chain compounds^{1,17}. The inter-chain coupling is rather significant for CuGeO₃, and CuSiO₃ can even be regarded as an anisotropic two-dimensional system. Since increasing inter-chain coupling tends to destabilize the spin-Peierls state¹⁸, a Néel ordered antiferromagnetic ground state might be expected for CuSiO₃ in contrast to the spin-Peierls state realized in CuGeO₃.

The obtained transfer integrals enables us to estimate the relevant exchange integrals J. This knowledge is crucial for the derivation and examination of magnetic model Hamiltonians of the spin-1/2 Heisenberg type frequently used in the literature:

$$H_{spin} = \sum_{ij}' J_{ij} \vec{S}_i \vec{S}_j \,. \tag{2}$$

In general, the total exchange J can be divided into an antiferromagnetic and a ferromagnetic contribution $J = J^{AFM} + J^{FM}$. In the strongly correlated limit, valid for typical cuprates, the former can be calculated in terms of the one-band extended Hubbard model J_{ij}^{AFM} $= 4t_{ij}^2/(U-V_{ij})$. The indices *i* and *j* correspond to nearest and next nearest neighbors, *U* is the on-site Coulomb repulsion and V_{ij} is the inter-site Coulomb interaction. From experimental data¹⁹ mapped from the standard *pd*model onto the one-band description, one estimates $U-V \sim 4.2$ eV. For the sake of simplicity, we neglect the difference in the quantity U - V in the compounds. The calculated values for the exchange integrals are given in Tab. II.

	\mathbf{J}_1^{AFM}	J_1	J_2	J_x	J_y	J_{yz}	μ_{th}	μ_{exp}
$CuGeO_3$	29	15	2.5	0.4	1.11	0.4	0.17	0.21
${\rm CuSiO}_3$	7.4	3.8	0.9	0.006	1.25	0.43	0.35	unknown

TABLE II. Exchange parameters J_i (in meV) for CuGeO₃ and CuSiO₃, and local magnetic moments (in μ_B) in the Néel state derived from them (see text). The experimental value μ_{ex} is an average over various studies mentioned in the text.

The value of the NN exchange integral $J_1^{AFM} \sim 30 \text{ meV}$ in $CuGeO_3$ exceeds the experimental values of about 11 meV from inelastic neutron scattering $data^{20}$, about 14 meV from magnetic susceptibility²¹ and about 22 meV from Raman scattering 22 . This points to a significant ferromagnetic contribution due to the Goodenough-Kanamori-Anderson-type interaction²³. In the following, we shall adopt 15 meV for the resulting total exchange coupling J_1 as a representative value, suggested by the average of the above mentioned experimental data. Owing to the lack of experimental data we assume the same ratio J_1/J_1^{AFM} in CuSiO₃ as in CuGeO₃, suggested by the quite similar O(2) 2p orbital occupancies mentioned above. For the latter compound, we note the reasonable agreement with the available experimental data and most of our calculated antiferromagnetic values for the remaining exchange parameters. Hence, further possible ferromagnetic contributions seem to be less relevant and are neglected in the following considerations.

Further simplification can be obtained mapping J_1 and the frustrated NN term J_2 onto an effective intra-chain coupling $J_{\parallel} = J_1 - 1.12 J_2$.²⁴ The calculated values for J_{\parallel} are 12.2 meV for CuGeO₃ and 2.8 meV for CuSiO₃, respectively. The latter value is close to the value of 2 meV reported by Baenitz *et al.* from a one-dimensional fit of magnetic susceptibility data.¹¹ We find also a considerable inter-chain frustration $J_{yz} = \beta J_y$ with β =0.36 (0.34) for the Ge- (Si-) compound. This is in good agreement with the suggestions of Uhrig⁸ $\beta \approx 0.5$ for CuGeO₃.

Transfering the above mentioned idea to map frustrating terms onto one effective coupling,²⁴ we adopt $J_{\perp} = J_y - 2J_{yz}$ for the effective inter-chain exchange parameters in b-direction. The factor of two is introduced to account approximately the twice as large number of second neighbors. The effective anisotropy ratio $R = J_{\perp}/J_{\parallel}$ measures approximately the magnitude of quantum fluctuations. In the crossover region between one and two dimensions, quantum fluctuations do strongly affect the magnitude of the staggered magnetization m and the local Cu moment $\mu = g_L n_d m$ at T = 0 for a Néel ground state, where $g_L=2.06$ to 2.26^{25} denotes the (anisotropic) Landé-factor (tensor) for Cu²⁺ in CuGeO₃ and $n_d \approx 0.8$ is the hole occupation number of the related Cu 3d plaquette orbital. Using the expression

$$m = 0.39\sqrt{R}(1+0.095R)\ln^{1/3}(1.3/R), \qquad (3)$$

taken from Ref. 26, we arrive at $0.17\mu_B$ in reasonable agreement²⁷ with the neutron data 0.22 ± 0.02^{28} and 0.2^{29} for the disorder induced Néel state achieved below 4.5K in Zn-doped CuGeO₃. The same approach predicts a significantly larger value of about $0.35\mu_B$ for CuSiO₃ realized in a possible Néel state.

To summarize, our LDA-FPLO calculation reveals valuable insight into the relevant couplings of CuGeO₃ and CuSiO₃. We can classify CuGeO₃ as a quasi onedimensional compound with significant inter-chain interaction, whereas CuSiO₃ is closer to an anisotropic twodimensional compound. The significantly reduced energy scale of the in-chain exchange interactions and the large inter-chain interaction in CuSiO_3 are less favorable for a spin-Peierls state than for a Néel order. However, due to the large frustrations other states such as a spin-Peierls state cannot be excluded. Further investigations are required to elucidate the unknown ground state.

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